











#### SN54LV00A, SN74LV00A

SCLS389K - SEPTEMBER 1997 - REVISED FEBRUARY 2015

# **Quadruple 2-Input Positive-NAND Gates**

#### **Features**

- 2-V to 5.5-V V<sub>CC</sub> Operation
- Max t<sub>pd</sub> of 6.5 ns at 5 V
- Typical V<sub>OLP</sub> (Output Ground Bounce)  $< 0.8 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)  $> 2.3 \text{ V at V}_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Support Mixed-Mode Voltage Operation on All Ports
- I<sub>off</sub> Supports Live Insertion, Partial Power Down Mode, and Back Drive Protection
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model
  - 200-V Machine Model
  - 1000-V Charged-Device Model

# 2 Applications

- Power Infrastructure
- **Network Switch**
- Automotive Infotainment
- Servers

# 3 Description

These quadruple 2-input positive-NAND gates are designed for 2-V to 5.5-V V<sub>CC</sub> operation.

The SNx4LV00A devices perform the boolean function  $Y = \overline{A \bullet B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	VQFN (14)	3.50 mm x 3.50 mm
	SOIC (14)	8.65 mm × 3.91 mm
SNx4LV00A	SOP (14)	10.30 mm x 5.30 mm
	SSOP (14)	6.20 mm x 5.30 mm
	TSSOP (14)	5.00 mm x 4.40 mm

<sup>(1)</sup> For all available packages, see the orderable addendum at the end of the data sheet.

# Simplified Schematic





# **Table of Contents**

1	Features 1	9	Detailed Description	9
2	Applications 1		9.1 Overview	9
3	Description 1		9.2 Functional Block Diagram	9
4	Simplified Schematic 1		9.3 Feature Description	9
5	Revision History2		9.4 Device Functional Modes	9
6	Pin Configuration and Functions	10	Application and Implementation	
7	Specifications4		10.1 Application Information	10
•	7.1 Absolute Maximum Ratings 4		10.2 Typical Application	10
	7.2 ESD Ratings	11	Power Supply Recommendations	11
	7.3 Recommended Operating Conditions	12	Layout	11
	7.4 Thermal Information		12.1 Layout Guidelines	11
	7.5 Electrical Characteristics 6		12.2 Layout Example	
	7.6 Switching Characteristics, V <sub>CC</sub> = 2.5 V ± 0.2 V 6	13	Device and Documentation Support	
	7.7 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V} \dots 6$		13.1 Related Links	12
	7.8 Switching Characteristics, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V} \dots 6$		13.2 Trademarks	12
	7.9 Noise Characteristics		13.3 Electrostatic Discharge Caution	12
	7.10 Operating Characteristics		13.4 Glossary	12
	7.11 Typical Characteristics	14	Mechanical, Packaging, and Orderable	
8	Parameter Measurement Information 8		Information	12

# 5 Revision History

#### Changes from Revision J (April 2005) to Revision K

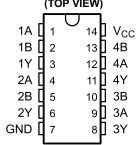
**Page** 

Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and 

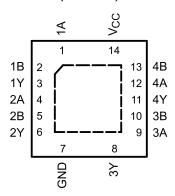


# 6 Pin Configuration and Functions

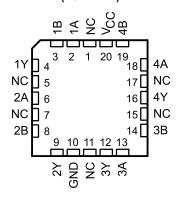
SN54LV00A . . . J OR W PACKAGE SN74LV00A . . . D, DB, DGV, NS, OR PW PACKAGE (TOP VIEW)



# SN74LV00A . . . RGY PACKAGE (TOP VIEW)



# SN54LV00A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

#### **Pin Functions**

	PIN	TYPE	DESCRIPTION
NO.	NAME	ITPE	DESCRIPTION
1	1A	1	1A Input
2	1B	I	1B Input
3	1Y	0	1Y Output
4	2A	I	2A Input
5	2B	I	2B Input
6	2Y	0	2Y Output
7	GND	_	GND
8	3Y	0	3Y Output
9	3A	1	3A Input
10	3B	1	3B Input
11	4Y	0	4Y Output
12	4A	I	4A Input
13	4B	I	4B Input
14	V <sub>CC</sub>	_	Power Pin

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# 7 Specifications

## 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	7	V
$V_{I}$	Input voltage range <sup>(2)</sup>		-0.5	7	V
Vo	Voltage range applied to any output in the high-impedar	nce or power-off state (2)	-0.5	7	V
Vo	Output voltage range <sup>(2)(3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
IO	Continuous output current	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### 7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	+2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	+1000	V

<sup>1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

<sup>(2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 5.5-V maximum.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



# 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			SN54LV	00A <sup>(2)</sup>	SN74LV	00A	
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5.5	2	5.5	V
		V <sub>CC</sub> = 2 V	1.5		1.5		
		V <sub>CC</sub> = 2.3 V to 2.7 V	V <sub>CC</sub> × 0.7		V <sub>CC</sub> <b>×</b> 0.7		
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V	V <sub>CC</sub> × 0.7		V <sub>CC</sub> <b>×</b> 0.7		V
		V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>CC</sub> × 0.7		V <sub>CC</sub> <b>×</b> 0.7		
		$V_{CC} = 2 V$		0.5		0.5	
		$V_{CC}$ = 2.3 V to 2.7 V		V <sub>CC</sub> × 0.3		V <sub>CC</sub> <b>×</b> 0.3	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		V <sub>CC</sub> × 0.3		V <sub>CC</sub> <b>×</b> 0.3	V
		V <sub>CC</sub> = 4.5 V to 5.5 V		V <sub>CC</sub> <b>×</b> 0.3		V <sub>CC</sub> <b>×</b> 0.3	
VI	Input voltage		0	5.5	0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
		$V_{CC} = 2 V$		-50		-50	μΑ
	High lovel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-2		-2	
ОН	High-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		-6		-6	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-12		-12	
		$V_{CC} = 2 V$		50		50	μΑ
	Low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2		2	
OL	Low-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		6		6	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		12		12	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		200		200	
∆t/Δv	Input transition rise or fall rate	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		100		100	ns/V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		20		20	
T <sub>A</sub>	Operating free-air temperature		-40	125	-40	125	°C

 <sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs* (SCBA004).
 (2) Product Preview.

#### 7.4 Thermal Information

				SNx4	LV00A			
	THERMAL METRIC <sup>(1)</sup>	D	DB	DGV	NS	PW	RGY	UNIT
		14 PINS						
$R_{\theta JA}$	Junction-to-ambient thermal resistance	90.6	107.1	129.0	90.7	122.6	57.5	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	50.9	59.6	521	48.3	51.4	70.8	
$R_{\theta JB}$	Junction-to-board thermal resistance	44.8	54.4	62.0	49.4	64.4	33.6	
ΨЈТ	Junction-to-top characterization parameter	14.7	20.5	6.5	14.6	6.7	34	°C/W
ΨЈВ	Junction-to-board characterization parameter	44.5	53.8	61.3	49.1	63.8	33.7	
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	_	_	_	_	_	13.9	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

Product Folder Links: SN54LV00A SN74LV00A



#### 7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	SN5	4LV00A <sup>(1)</sup>		-40°C to 8 SN74LV0		-40°C to SN74LV		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
	I <sub>OH</sub> = -50 μA	2 V to 5.5 V	V <sub>CC</sub> - 0.1			V <sub>CC</sub> - 0.1		V <sub>CC</sub> – 0.1		
$V_{OH}$	$I_{OH} = -2 \text{ mA}$	2.3 V	2			2		2		V
	$I_{OH} = -6 \text{ mA}$	3 V	2.48			2.48		2.48		
	I <sub>OH</sub> = -12 mA	4.5 V	3.8			3.8		3.8		
	I <sub>OL</sub> = 50 μA	2 V to 5.5 V			0.1		0.1		0.1	
$V_{OL}$	I <sub>OL</sub> = 2 mA	2.3 V			0.4		0.4		0.4	V
	$I_{OL} = 6 \text{ mA}$	3 V			0.44		0.44		0.44	
	I <sub>OL</sub> = 12 mA	4.5 V			0.55		0.55		0.55	
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 to 5.5 V			±1		±1		±1	μΑ
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			20		20		20	μΑ
I <sub>off</sub>	$V_I$ or $V_O = 0$ to 5.5 V	0			5		5		5	μΑ
C	V – V or CND	3.3 V		3.3				3.3		pF
$C_{i}$	$V_I = V_{CC}$ or GND	5 V		3.3				3.3		þг

<sup>(1)</sup> Product Preview.

# 7.6 Switching Characteristics, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE		T <sub>A</sub> = 25°	C	SN54LV	/00A <sup>(1)</sup>	-40°C to SN74L		-40°C to 12 SN74LV00		UNIT
	(INFUI)	(001701)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX			
	۸	V	C <sub>L</sub> = 15 pF		7.1 <sup>(2)</sup>	12.9 <sup>(2)</sup>	1 <sup>(2)</sup>	16 <sup>(2)</sup>	1	15	1	16	
τ <sub>pd</sub>	А	Y	C <sub>L</sub> = 50 pF		9.6	16.6	1	21	1	20	1	21	ns

<sup>(1)</sup> Product Preview.

# 7.7 Switching Characteristics, $V_{CC}$ = 3.3 V ± 0.3 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARA	METER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE		T <sub>A</sub> = 25°C	;	SN54L\	/00A <sup>(1)</sup>	-40°C to SN74L		-40°C to SN74L		UNIT
		(INFUT)	(001701)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		^	V	C <sub>L</sub> = 15 pF		5 <sup>(2)</sup>	7.9 <sup>(2)</sup>	1 <sup>(2)</sup>	10.5(2)	1	9.5	1	10.5	20
	<sup>l</sup> pd	А	ĭ	$C_L = 50 \text{ pF}$		6.9	11.4	1	14	1	13	1	14	ns

<sup>(1)</sup> Product Preview.

# 7.8 Switching Characteristics, $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE		T <sub>A</sub> = 25°0	;	SN54LV	′00A <sup>(1)</sup>	-40°C to SN74L		-40°C to SN74L		UNIT
	(INPUT)	(001701)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
	۸	V	C <sub>L</sub> = 15 pF		3.6 <sup>(2)</sup>	5.5 <sup>(2)</sup>	1 <sup>(3)</sup>	7.5 <sup>(3)</sup>	1	6.5	1	7	
T <sub>pd</sub>	A	ľ	C <sub>L</sub> = 50 pF		4.9	7.5	1	9.5	1	8.5	1	9	ns

Product Preview.

2) On products compliant to MIL-PRF-38535, this parameter is not production tested.

(3) On products compliant to MIL-PRF-38535, this parameter is not production tested.

<sup>(2)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

<sup>(2)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.



# 7.9 Noise Characteristics(1)

 $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$ 

	PARAMETER	SN	74LV04A		UNIT
	PARAWEIER	MIN	TYP	MAX	UNII
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.2	8.0	V
$V_{OL(V)}$	Quiet output, minimum dynamic V <sub>OL</sub>		-0.1	-0.8	V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		3.1		V
$V_{IH(D)}$	High-level dynamic input voltage	2.31			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.99	V

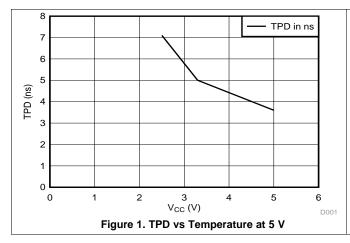
<sup>(1)</sup> Characteristics are for surface-mount packages only.

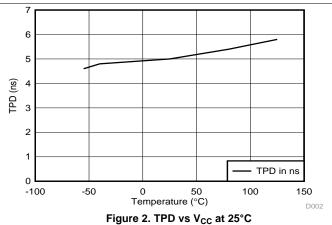
# 7.10 Operating Characteristics

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST C	ONDITIONS	V <sub>CC</sub>	TYP	UNIT
_	Dower dissination conscitones	C 50 ~ F	f 40 MHz	3.3 V	9.5	،
C <sub>pd</sub>	Power dissipation capacitance	$C_L = 50 \text{ pF},$	f = 10 MHz	5 V	11	p⊦

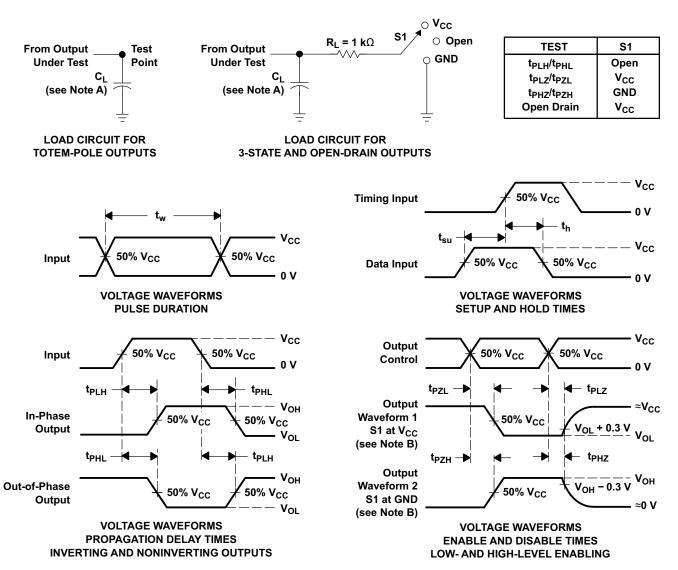
# 7.11 Typical Characteristics







#### 8 Parameter Measurement Information



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  3 ns.  $t_f \leq$  3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



# 9 Detailed Description

#### 9.1 Overview

These quadruple 2-input positive-NAND gates are designed for 2-V to 5.5-V V<sub>CC</sub> operation.

The SNx4LV00A devices perform the boolean function  $Y = \overline{A \bullet B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic

These devices are fully specified for partial-power-down application using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

#### 9.2 Functional Block Diagram



## 9.3 Feature Description

- Wide operating voltage range
  - Operates from 2 V to 5.5 V
- Allows down voltage translation
  - Inputs accept voltages to 5.5 V
- I<sub>off</sub> feature allows voltages on the input or output when V<sub>CC</sub> is 0 V.

#### 9.4 Device Functional Modes

Table 1. Function Table (Each Gate)

INF	OUTPUT	
Α	В	Υ
Н	Н	L
L	X	Н
X	L	Н

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# 10 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 10.1 Application Information

The SN74LV00A is a Low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs can accept voltages to 5.5~V at any valid  $V_{CC}$  making it Ideal for down translation.

## 10.2 Typical Application

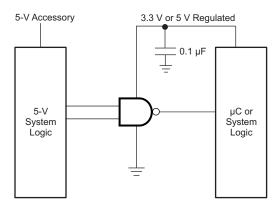


Figure 4. Typical Application Schematic

#### 10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

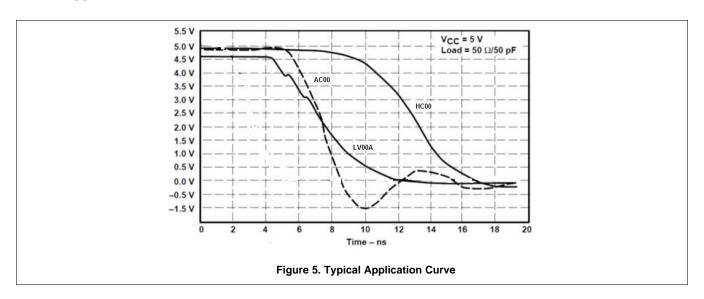
### 10.2.2 Detailed Design Procedure

- 1. Recommended Input Condition
  - Specified high and low levels, see V<sub>IH</sub> and V<sub>IL</sub> in the Recommended Operating Conditions table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V<sub>CC</sub>.
- 2. Recommend Output Conditions
  - Load currents should not exceed 25 mA per output and 50 mA total for the part.
  - Outputs should not be pulled above V<sub>CC</sub>.



#### **Typical Application (continued)**

#### 10.2.3 Application Curves



# 11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Recommended Operating Conditions table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1  $\mu$ F capacitor is recommended. If there are multiple  $V_{CC}$  pins, 0.01  $\mu$ F or 0.022  $\mu$ F capacitors are recommended for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1  $\mu$ F and 1  $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

#### 12 Layout

#### 12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$  whichever make more sense or is more convenient. It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the I.O's so they also cannot float when disabled.

### 12.2 Layout Example

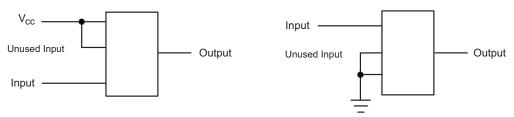


Figure 6. Layout Diagram

Product Folder Links: SN54LV00A SN74LV00A



# 13 Device and Documentation Support

#### 13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74LV04A	Click here	Click here	Click here	Click here	Click here	

#### 13.2 Trademarks

All trademarks are the property of their respective owners.

### 13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV00AD	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125	LV00A	
SN74LV00ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV00A	Samples
SN74LV00ADGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV00A	Samples
SN74LV00ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	LV00A	Samples
SN74LV00ANSR	ACTIVE	SOP	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV00A	Samples
SN74LV00APW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125	LV00A	
SN74LV00APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	LV00A	Samples
SN74LV00APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV00A	Samples
SN74LV00APWT	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125	LV00A	
SN74LV00ARGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LV00A	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



# **PACKAGE OPTION ADDENDUM**

www.ti.com 2-Dec-2024

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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www.ti.com 7-Dec-2024

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV00ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LV00ADGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV00ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV00ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV00ANSR	SOP	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LV00APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV00APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV00ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



www.ti.com 7-Dec-2024



## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV00ADBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74LV00ADGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74LV00ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LV00ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LV00ANSR	SOP	NS	14	2000	356.0	356.0	35.0
SN74LV00APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV00APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV00ARGYR	VQFN	RGY	14	3000	356.0	356.0	35.0

# DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



# RGY (S-PVQFN-N14)

# PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-2/P 03/14

NOTE: All linear dimensions are in millimeters



# RGY (S-PVQFN-N14)

# PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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